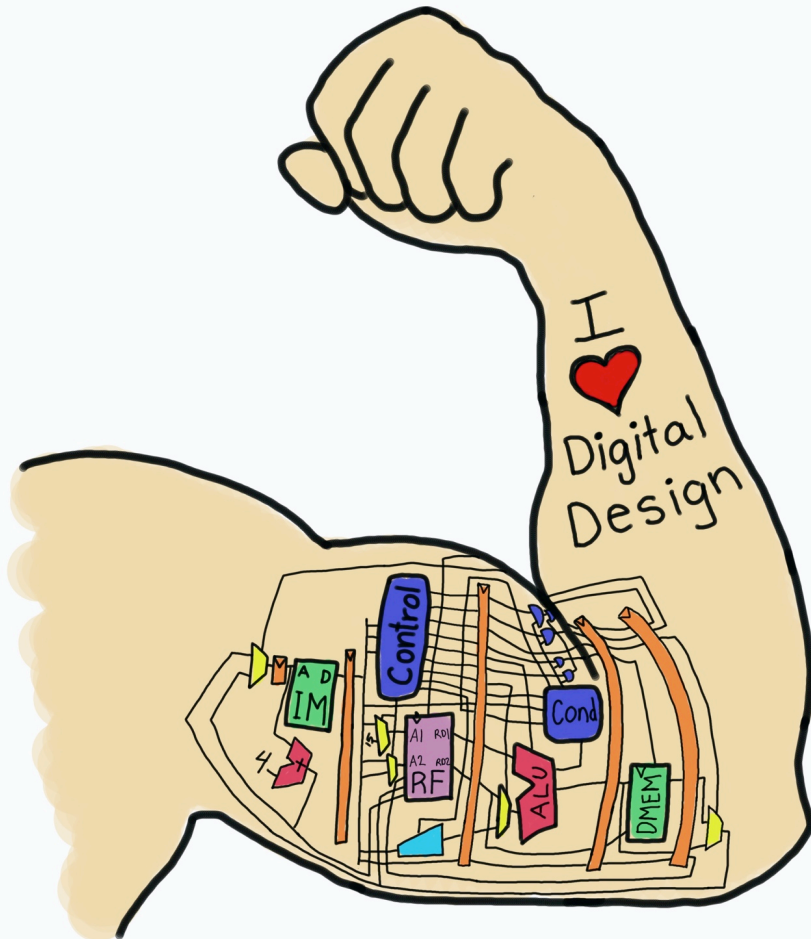


# E85 Digital Design & Computer Engineering



## Lecture 1: Logic Gates & Analog Behavior of Digital Systems

**HARVEY  
MUDD  
COLLEGE**

# Lecture 1

- **Logic Gates**
- **Verilog**
- **Logic Levels**
- **CMOS Transistors**
- **Power Consumption**
- **Datasheets**



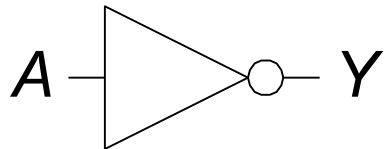
# Logic Gates

- **Perform logic functions:**
  - inversion (NOT), AND, OR, NAND, NOR, etc.
- **Single-input:**
  - NOT gate, buffer
- **Two-input:**
  - AND, OR, XOR, NAND, NOR, XNOR
- **Multiple-input**



# Single-Input Logic Gates

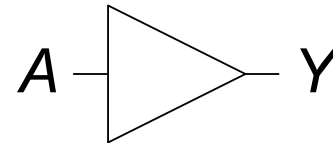
## NOT



$$Y = \overline{A}$$

A	Y
0	1
1	0

## BUF



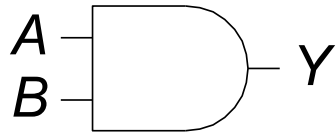
$$Y = A$$

A	Y
0	0
1	1



# Two-Input Logic Gates

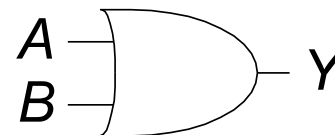
## AND



$$Y = AB$$

A	B	Y
0	0	
0	1	
1	0	
1	1	

## OR



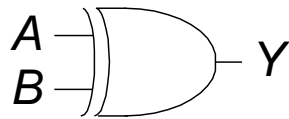
$$Y = A + B$$

A	B	Y
0	0	
0	1	
1	0	
1	1	



# More Two-Input Logic Gates

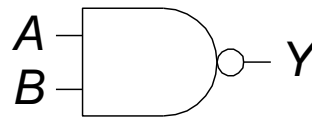
## XOR



$$Y = A \oplus B$$

A	B	Y
0	0	0
0	1	1
1	0	1
1	1	0

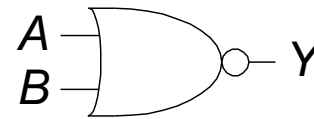
## NAND



$$Y = \overline{AB}$$

A	B	Y
0	0	1
0	1	1
1	0	1
1	1	0

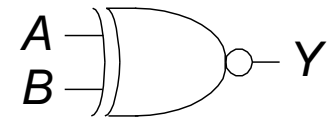
## NOR



$$Y = \overline{A + B}$$

A	B	Y
0	0	1
0	1	0
1	0	0
1	1	0

## XNOR



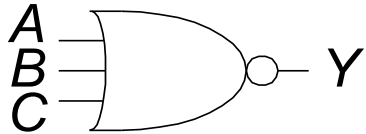
$$Y = \overline{A \oplus B}$$

A	B	Y
0	0	1
0	1	0
1	0	0
1	1	1



# Multiple-Input Logic Gates

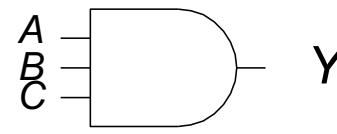
## NOR3



$$Y = \overline{A+B+C}$$

A	B	C	Y
0	0	0	
0	0	1	
0	1	0	
0	1	1	
1	0	0	
1	0	1	
1	1	0	
1	1	1	

## AND3



$$Y = ABC$$

A	B	C	Y
0	0	0	
0	0	1	
0	1	0	
0	1	1	
1	0	0	
1	0	1	
1	1	0	
1	1	1	

- Multi-input XOR: Odd parity (true if odd number of inputs are true)



# SystemVerilog Description

```
module gates(input  logic a, b, c,  
             output logic y1, y2, y3, y4, y5);  
  
    not  g1(y1, a);  
    and  g2(y2, a, b);  
    or   g3(y3, a, b, c);  
    nand g4(y4, b, c);  
    xor  g5(y5, a, c);  
endmodule
```





# Logic Levels

- Discrete voltages represent 1 and 0
- For example:
  - 0 = *ground* (GND) or 0 volts
  - 1 =  $V_{DD}$  or 5 volts
- What about 4.99 volts? Is that a 0 or a 1?
- What about 3.2 volts?



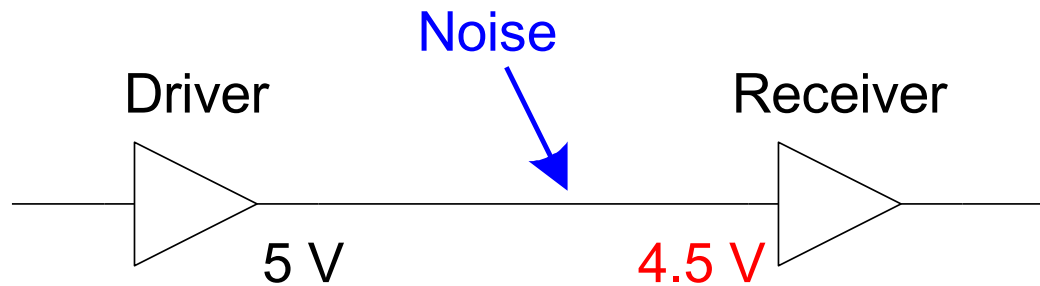
# Logic Levels

- *Range* of voltages for 1 and 0
- Different ranges for inputs and outputs to allow for *noise*



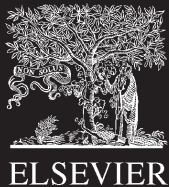
# What is Noise?

- **Anything that degrades the signal**
  - E.g., resistance, power supply noise, coupling to neighboring wires, etc.
- **Example:** a gate (driver) outputs 5 V but, because of resistance in a long wire, receiver gets 4.5 V

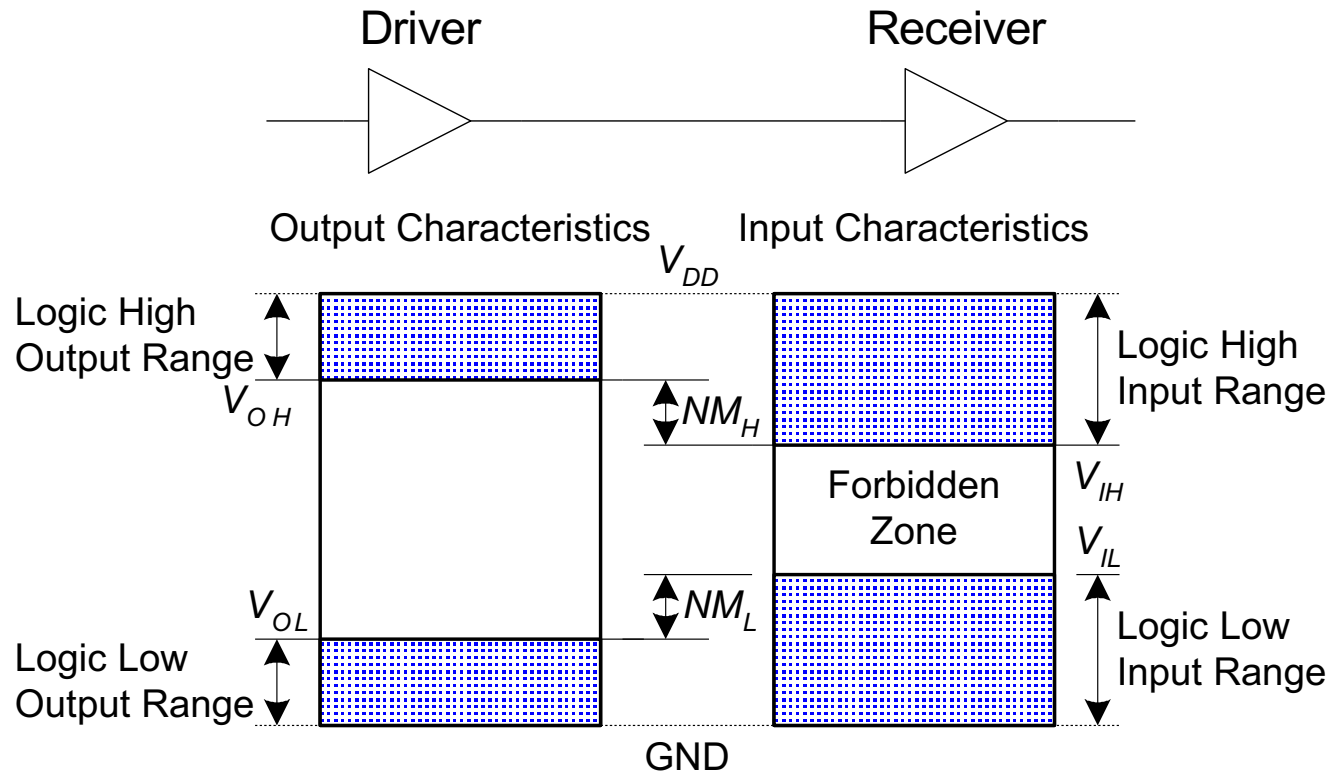


# The Static Discipline

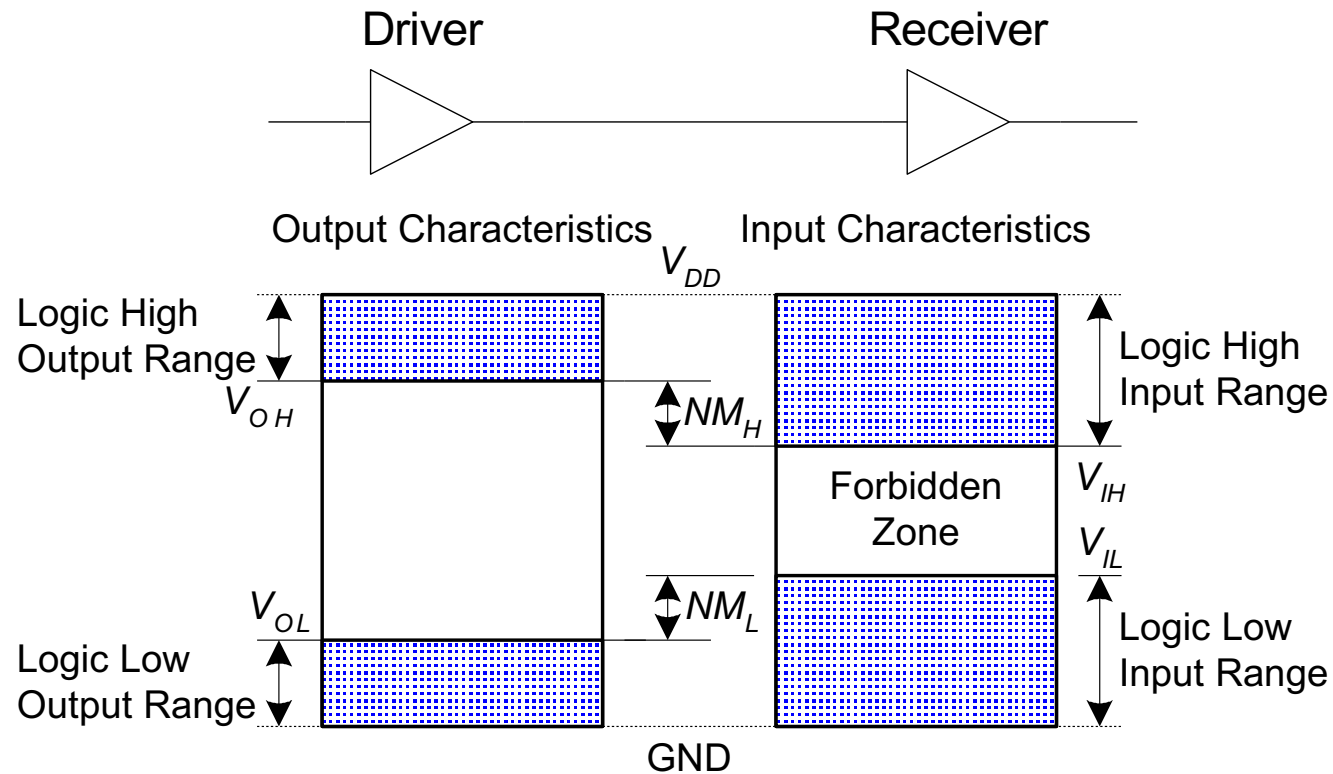
- With logically valid inputs, every circuit element must produce logically valid outputs
- Use limited ranges of voltages to represent discrete values



# Noise Margins



# Noise Margins



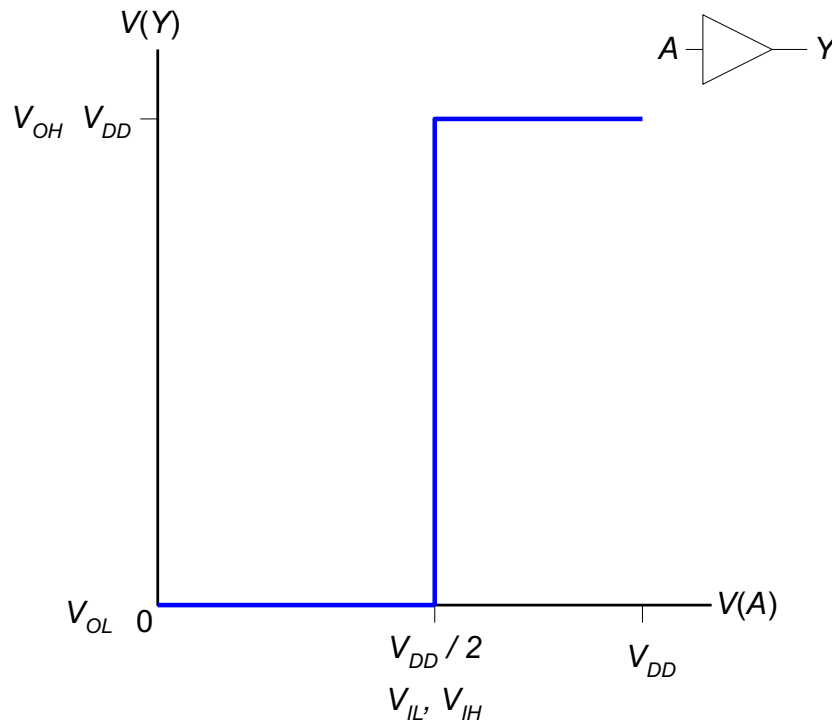
**High Noise Margin:  $NM_H =$**

**Low Noise Margin:  $NM_L =$**



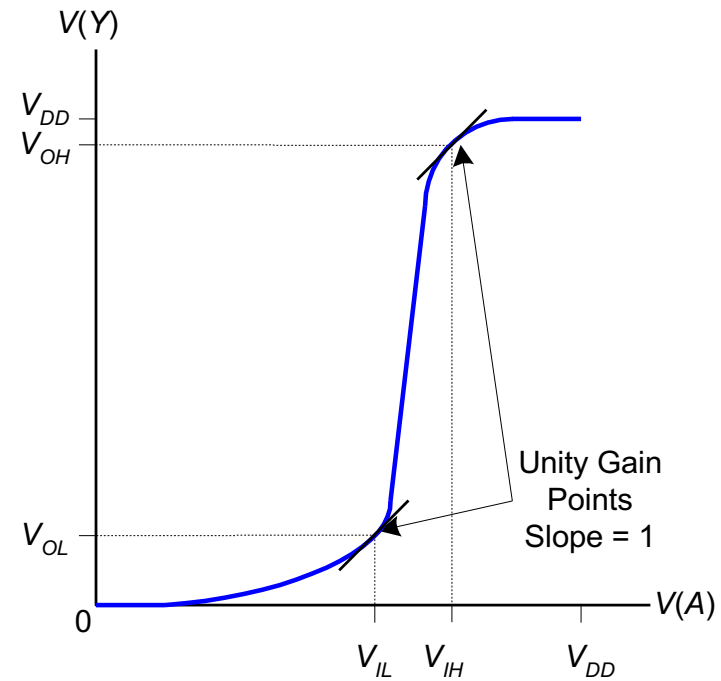
# DC Transfer Characteristics

## Ideal Buffer:



$$NM_H = NM_L = V_{DD}/2$$

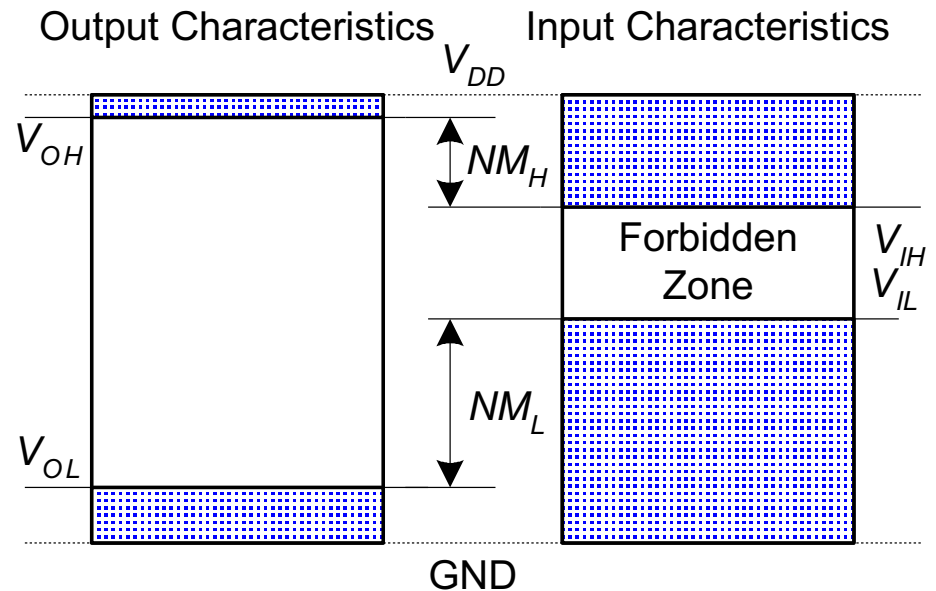
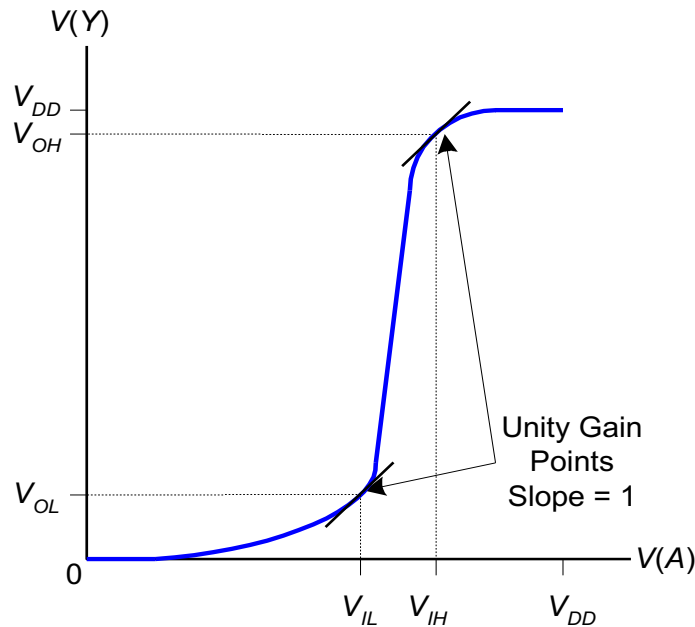
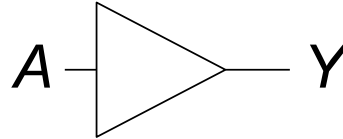
## Real Buffer:



$$NM_H, NM_L < V_{DD}/2$$



# DC Transfer Characteristics





# $V_{DD}$ Scaling

- In 1970's and 1980's,  $V_{DD} = 5\text{ V}$
- $V_{DD}$  has dropped
  - Avoid frying tiny transistors
  - Save power
- 3.3 V, 2.5 V, 1.8 V, 1.5 V, 1.2 V, 1.0 V, ...
  - Be careful connecting chips with different supply voltages



# $V_{DD}$ Scaling

- In 1970's and 1980's,  $V_{DD} = 5\text{ V}$
- $V_{DD}$  has dropped
  - Avoid frying tiny transistors
  - Save power
- 3.3 V, 2.5 V, 1.8 V, 1.5 V, 1.2 V, 1.0 V, ...
  - Be careful connecting chips with different supply voltages

**Chips operate because they contain magic smoke**

**Proof:** if the magic smoke is let out, the chip stops working



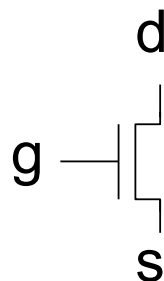
# Logic Family Examples

Logic Family	$V_{DD}$	$V_{IL}$	$V_{IH}$	$V_{OL}$	$V_{OH}$
<b>TTL</b>	5 (4.75 - 5.25)	0.8	2.0	0.4	2.4
<b>CMOS</b>	5 (4.5 - 6)	1.35	3.15	0.33	3.84
<b>LVTTL</b>	3.3 (3 - 3.6)	0.8	2.0	0.4	2.4
<b>LVC MOS</b>	3.3 (3 - 3.6)	0.9	1.8	0.36	2.7

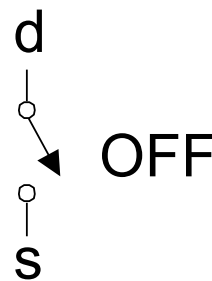


# Transistors

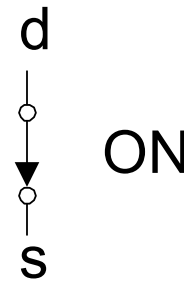
- Logic gates built from transistors
- 3-ported voltage-controlled switch
  - 2 ports connected depending on voltage of 3rd
  - d and s are connected (ON) when g is 1



$g = 0$

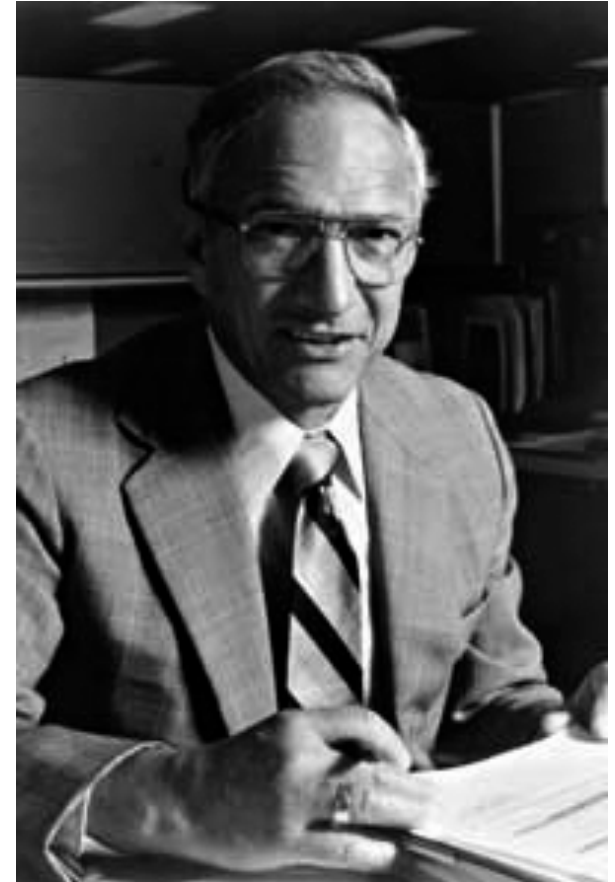


$g = 1$



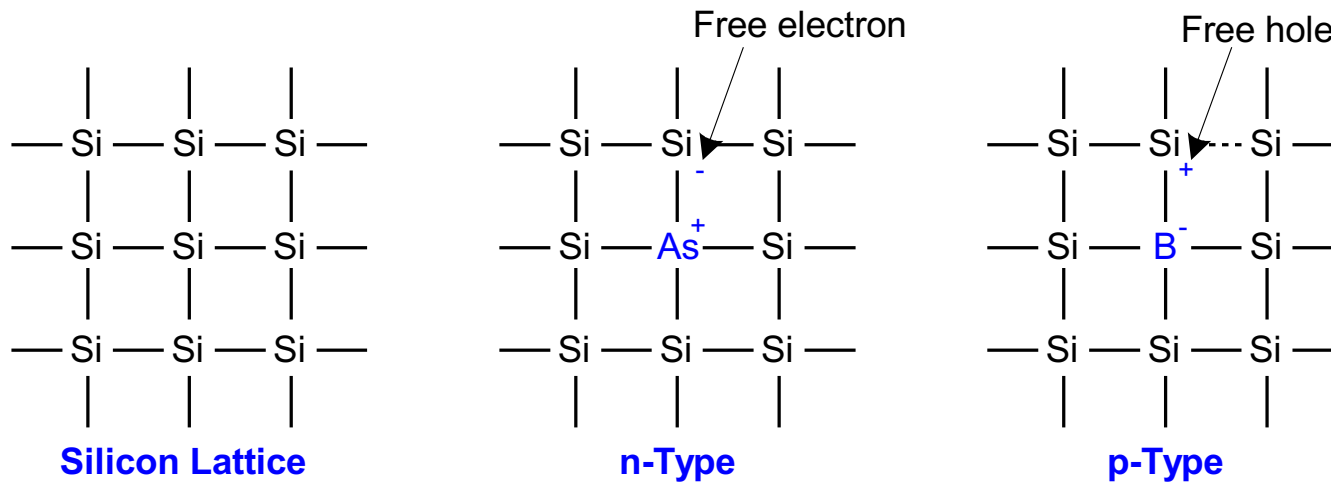
# Robert Noyce, 1927-1990

- Nicknamed “Mayor of Silicon Valley”
- Cofounded Fairchild Semiconductor in 1957
- Cofounded Intel in 1968
- Co-invented the integrated circuit



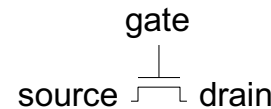
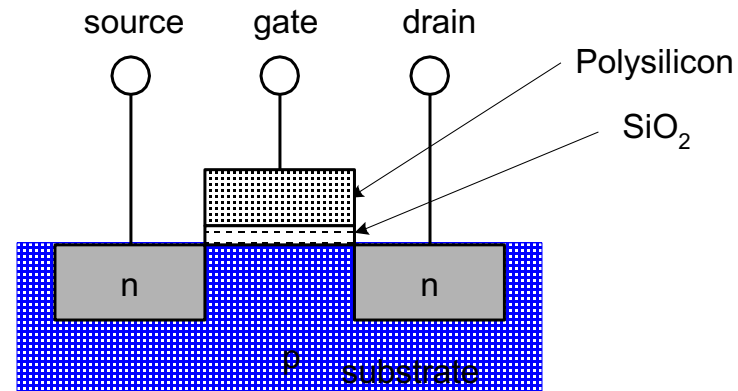
# Silicon

- Transistors built from silicon, a semiconductor
- Pure silicon is a poor conductor (no free charges)
- Doped silicon is a good conductor (free charges)
  - n-type (free **n**egative charges, electrons)
  - p-type (free **p**ositive charges, holes)



# MOS Transistors

- **Metal oxide silicon (MOS) transistors:**
  - Polysilicon (used to be **metal**) gate
  - **Oxide** (silicon dioxide) insulator
  - Doped **silicon**



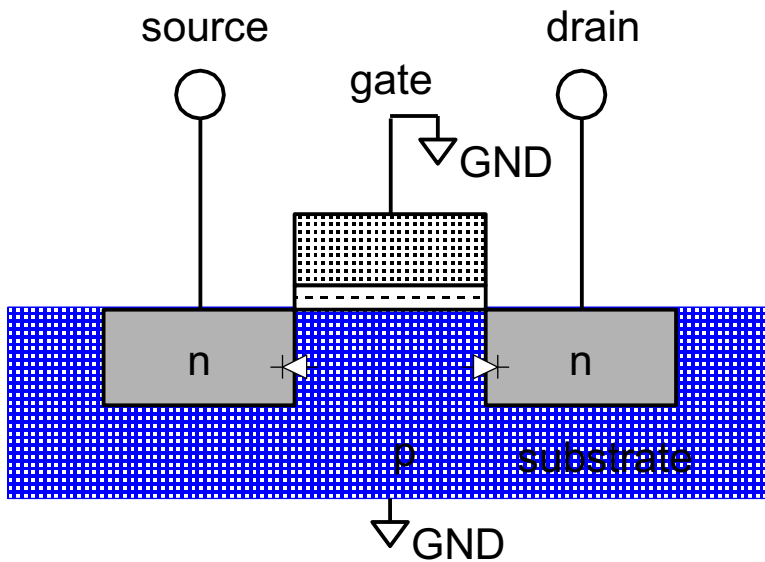
nMOS



# Transistors: nMOS

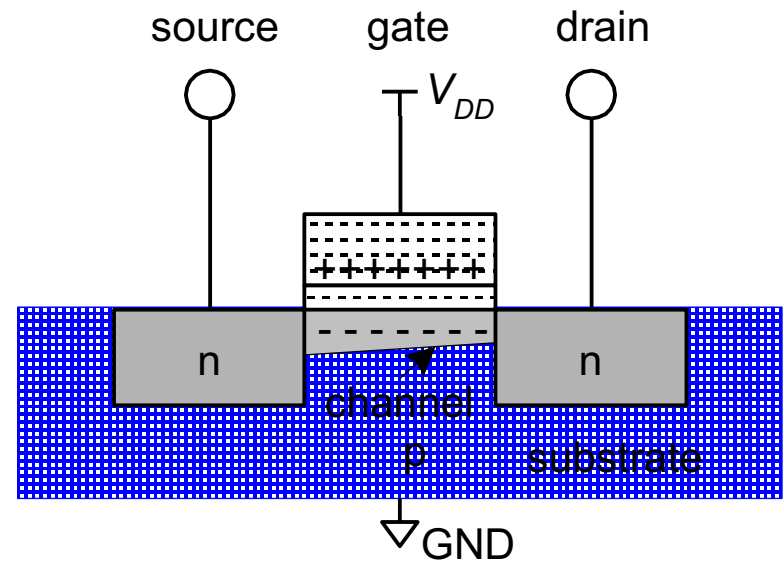
## Gate = 0

**OFF** (no connection between source and drain)



## Gate = 1

**ON** (channel between source and drain)

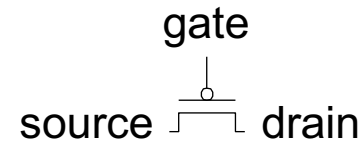
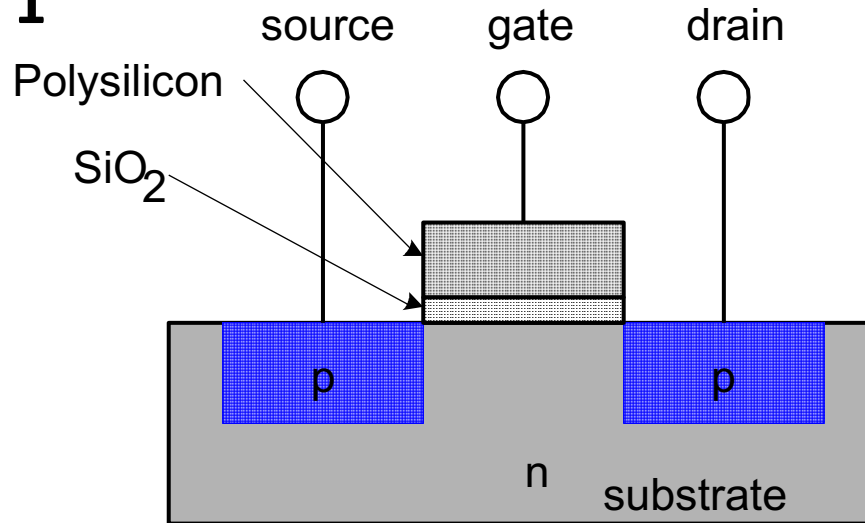




# Transistors: pMOS

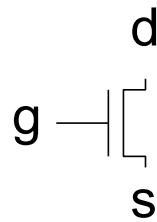
## pMOS transistor is opposite

- **ON** when **Gate = 0**
- **OFF** when **Gate = 1**

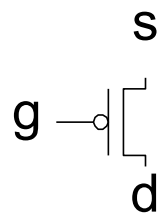


# Transistor Function

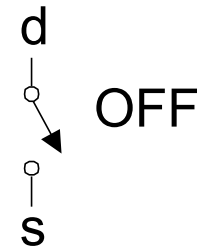
nMOS



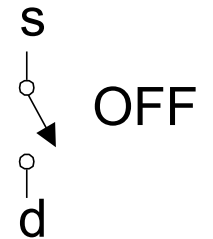
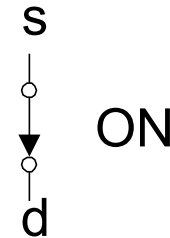
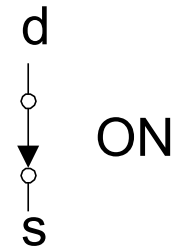
pMOS



$g = 0$

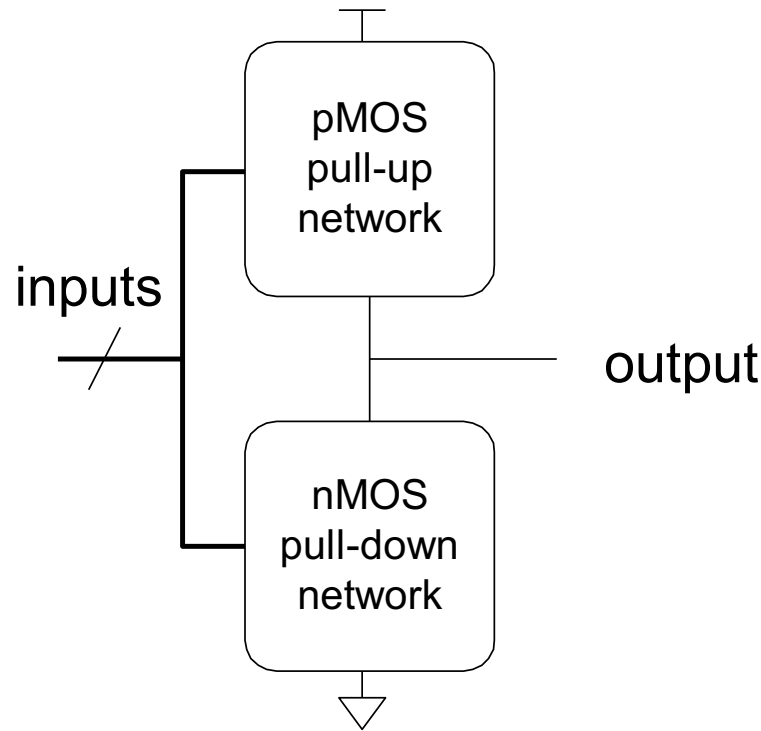


$g = 1$



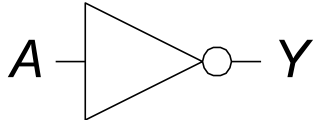
# Transistor Function

- **nMOS**: pass good **0**'s, so connect source to GND
- **pMOS**: pass good **1**'s, so connect source to  $V_{DD}$



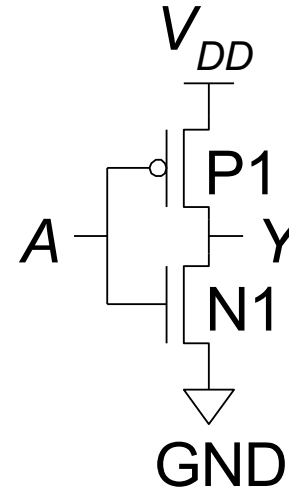
# CMOS Gates: NOT Gate

**NOT**



$$Y = \overline{A}$$

<i>A</i>	<i>Y</i>
0	1
1	0

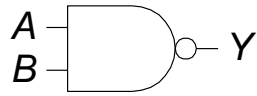


<i>A</i>	<i>P1</i>	<i>N1</i>	<i>Y</i>
0			
1			



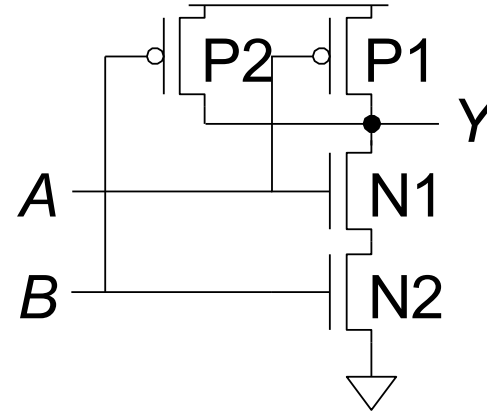
# CMOS Gates: NAND Gate

## NAND



$$Y = \overline{AB}$$

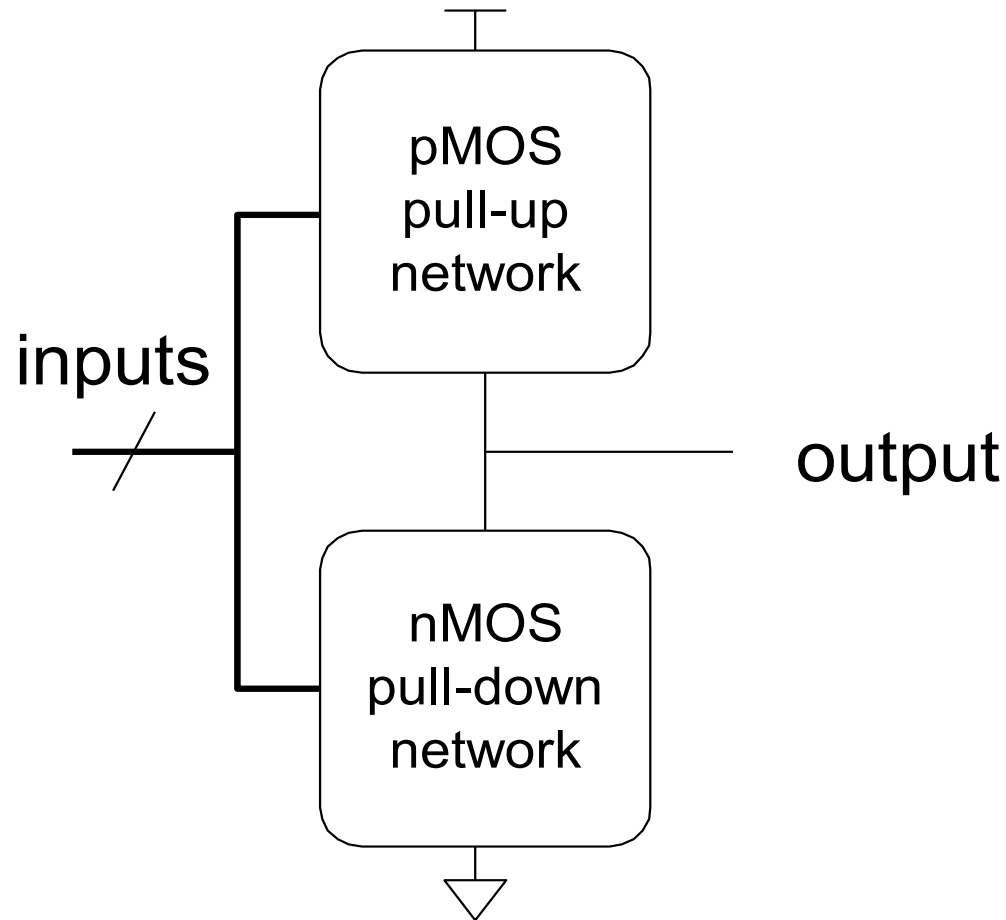
A	B	Y
0	0	1
0	1	1
1	0	1
1	1	0



A	B	P1	P2	N1	N2	Y
0	0					
0	1					
1	0					
1	1					



# CMOS Gate Structure



# NOR3 Gate

How do you build a three-input NOR gate?



# AND2 Gate

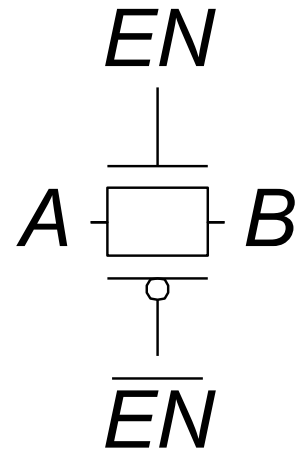
How do you build a two-input AND gate?





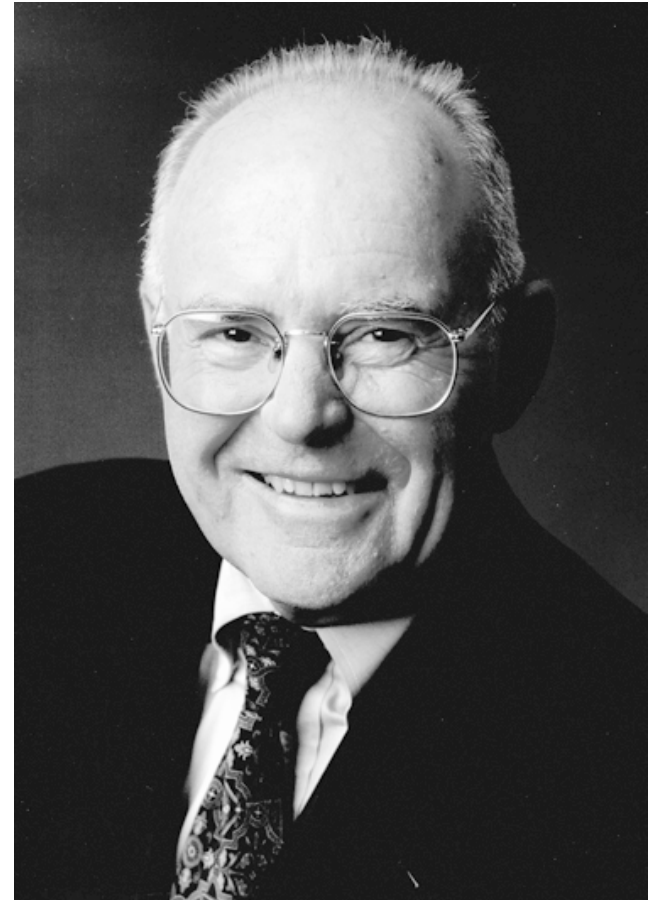
# Transmission Gates

- nMOS pass 1's poorly
- pMOS pass 0's poorly
- Transmission gate is a better switch
  - passes both 0 and 1 well
- When  $EN = 1$ , the switch is ON:
  - $EN = 0$  and  $A$  is connected to  $B$
- When  $EN = 0$ , the switch is OFF:
  - $A$  is not connected to  $B$

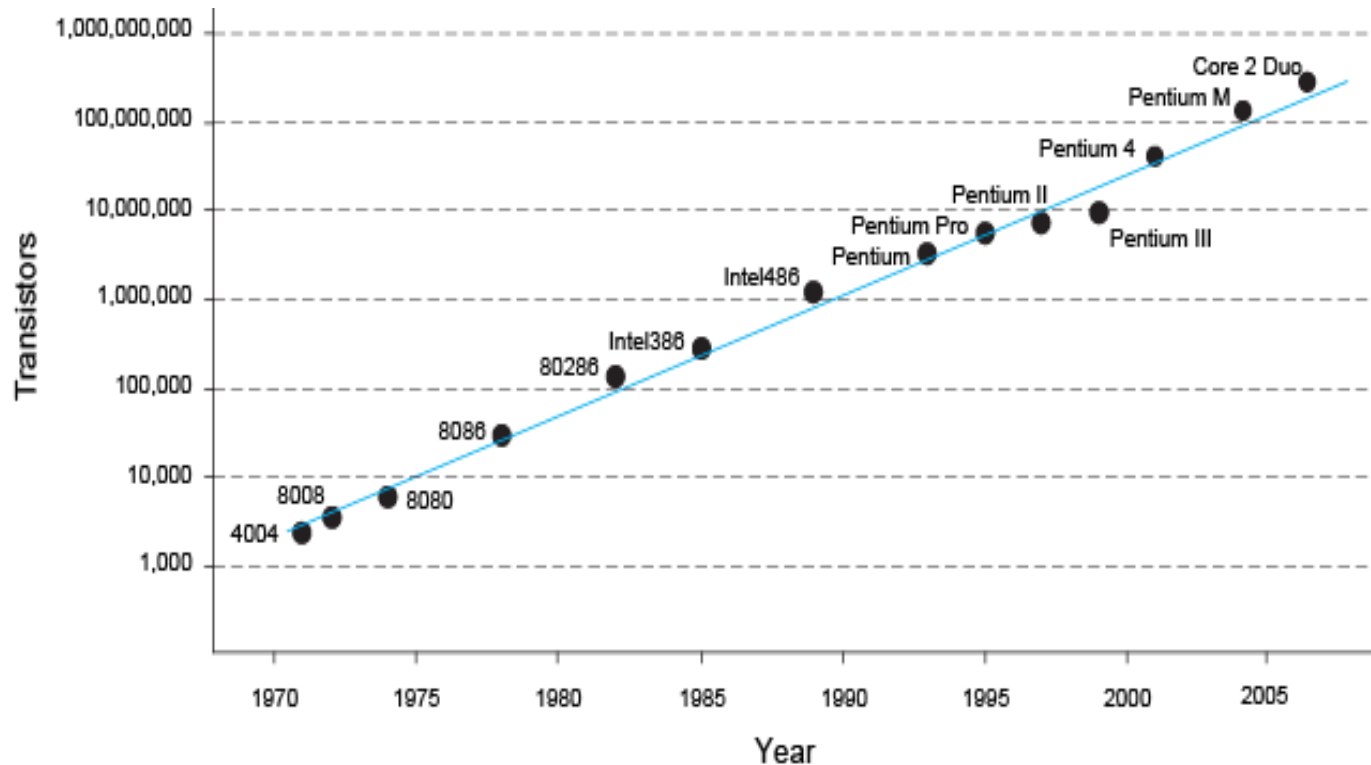


# Gordon Moore, 1929-

- Cofounded Intel in 1968 with Robert Noyce.
- **Moore's Law:** number of transistors on a computer chip doubles every year (observed in 1965)
- Since 1975, transistor counts have doubled every two years.



# Moore's Law



*“If the automobile had followed the same development cycle as the computer, a Rolls-Royce would today cost \$100, get one million miles to the gallon, and explode once a year . . .” (Robert Cringely, Infoworld)*

*– Robert Cringely*



# Power Consumption

**Power = Energy consumed per unit time**

- Dynamic power consumption
- Static power consumption



# Dynamic Power Consumption

- **Power to charge transistor gate capacitances**
  - Energy required to charge a capacitance,  $C$ , to  $V_{DD}$  is  $CV_{DD}^2$
  - Circuit running at frequency  $f$ : transistors switch (from 1 to 0 or vice versa) at that frequency
  - Capacitor is charged  $f/2$  times per second (discharging from 1 to 0 is free)
- **Dynamic power consumption:**

$$P_{dynamic} = \frac{1}{2}CV_{DD}^2f$$



# Static Power Consumption

- Power consumed when no gates are switching
- Caused by the *quiescent supply current*,  $I_{DD}$  (also called the *leakage current*)
- Static power consumption:

$$P_{static} = I_{DD}V_{DD}$$



# Power Consumption Example

- Estimate the power consumption of a mobile phone running Angry Birds
  - $V_{DD} = 0.8 \text{ V}$
  - $C = 5 \text{ nF}$
  - $f = 2 \text{ GHz}$
  - $I_{DD} = 10 \text{ mA}$

$$\begin{aligned} P &= \frac{1}{2}CV_{DD}^2f + I_{DD}V_{DD} \\ &= \frac{1}{2}(5 \text{ nF})(0.8 \text{ V})^2(2 \text{ GHz}) + (10 \text{ mA})(0.8 \text{ V}) \\ &= (3.2 + 0.008) \text{ W} \approx 3.2 \text{ W} \end{aligned}$$



# Datasheets

- Datasheets are a contract between the manufacturer and the user.

- 74LS04 has six NOT gates

- Pinout

- Input A, output Y
- Also hook up VCC and GND

74-series are logic gates

LS: Low power Shottky

HC: High speed CMOS

04: six NOT gates



## SN5404, SN54LS04, SN54S04, SN7404, SN74LS04, SN74S04 HEX INVERTERS

SDL5029C - DECEMBER 1983 - REVISED JANUARY 2004

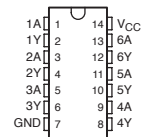
- Dependable Texas Instruments Quality and Reliability

### description/ordering information

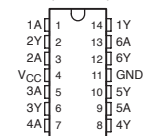
These devices contain six independent inverters.

SN5404 . . . J PACKAGE  
SN54LS04, SN54S04 . . . J OR W PACKAGE  
SN7404, SN74S04 . . . D, N, OR NS PACKAGE  
SN74LS04 . . . D, DB, N, OR NS PACKAGE

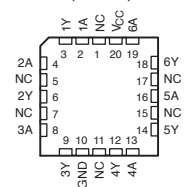
(TOP VIEW)



SN5404 . . . W PACKAGE  
(TOP VIEW)



SN54LS04, SN54S04 . . . FK PACKAGE  
(TOP VIEW)



NC - No internal connection



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

TEXAS  
INSTRUMENTS

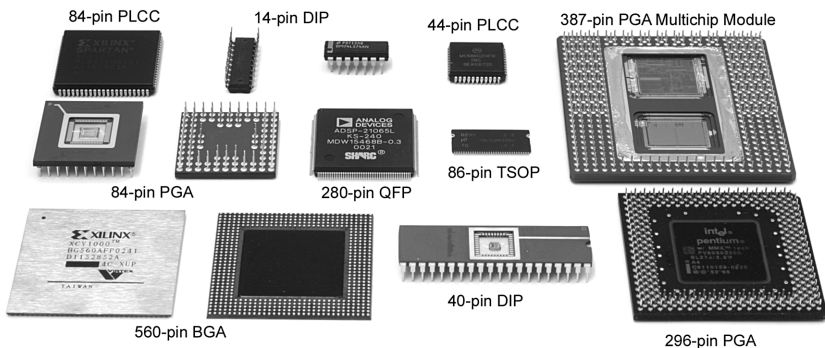
POST OFFICE BOX 655303 • DALLAS, TEXAS 75265

Copyright © 2004, Texas Instruments Incorporated. On products compliant to MIL-PRF-38535, all parameters are tested unless otherwise noted. On all other products, production processing does not necessarily include testing of all parameters.



# Datasheets

- Chips are available in plastic or ceramic packages with different temperature ratings.
- Dual Inline Package (DIP)
- Small Outline IC (SOIC)
- Small Outline Package (SOP)
- Leadless Chip Carrier (LCC)



## SN5404, SN54LS04, SN54S04, SN7404, SN74LS04, SN74S04 HEX INVERTERS

SDLS028C - DECEMBER 1983 - REVISED JANUARY 2004

### ORDERING INFORMATION

TA	PACKAGE†	ORDERABLE PART NUMBER	TOP-SIDE MARKING	
0°C to 70°C	PDIP - N	Tube	SN7404N	
		Tube	SN74LS04N	
		Tube	SN74S04N	
	SOIC - D	Tube	SN7404D	7404
		Tape and reel	SN7404DR	
		Tube	SN74LS04D	LS04
		Tape and reel	SN74LS04DR	
		Tube	SN74S04D	S04
		Tape and reel	SN74S04DR	
	SOP - NS	Tape and reel	SN7404NSR	SN7404
		Tape and reel	SN74LS04NSR	74LS04
	SSOP - DB	Tape and reel	SN74LS04NSR	74LS04
Tape and reel		SN74LS04DBR	LS04	
-55°C to 125°C	CDIP - J	Tube	SN5404J	
		Tube	SNJ5404J	
		Tube	SN54LS04J	
		Tube	SN54S04J	
		Tube	SNJ54LS04J	
		Tube	SNJ54S04J	
	CFP - W	Tube	SNJ5404W	
		Tube	SNJ54S04W	
	LCCC - FK	Tube	SNJ54LS04FK	
		Tube	SNJ54S04FK	

† Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at [www.ti.com/sc/package](http://www.ti.com/sc/package).

### FUNCTION TABLE (each inverter)

INPUT A	OUTPUT Y
H	L
L	H



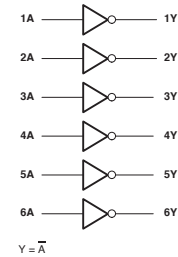
# Datasheets

- Six NOT gates
- Input A, output Y

SN5404, SN54LS04, SN54S04,  
SN7404, SN74LS04, SN74S04  
HEX INVERTERS

SDLS029C - DECEMBER 1983 - REVISED JANUARY 2004

logic diagram (positive logic)



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3

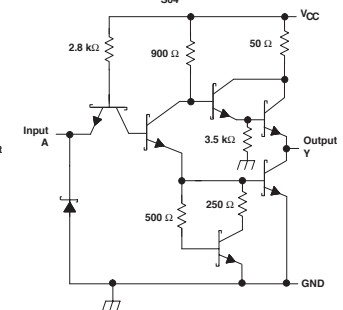
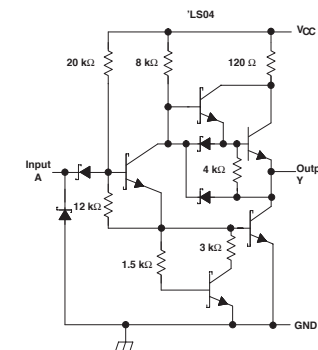
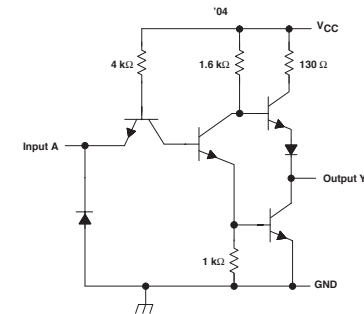


# Datasheets

- Internal structure
  - Not too important for you.
  - NPN transistor at middle and resistors above and below comprise the inverter
  - NPN transistors on right form an output stage for driving more current

SN5404, SN54LS04, SN54S04,  
SN7404, SN74LS04, SN74S04  
HEX INVERTERS  
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schematics (each gate)



Resistor values shown are nominal.

4

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# Datasheets

- Absolute Maximums specify when the chip will catch on fire or suffer permanent damage. It is not guaranteed to function correctly near these levels. Don't use for design purposes.
- Recommended Operating Conditions say how it should be used.
- Different vendors have different names for conditions
  - Use some common sense to interpret

## SN5404, SN54LS04, SN54S04, SN7404, SN74LS04, SN74S04 HEX INVERTERS

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### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, $V_{CC}$ (see Note 1) .....	7 V
Input voltage, $V_i$ : '04, 'S04 .....	5.5 V
LS04 .....	7 V
Package thermal impedance, $\theta_{JA}$ (see Note 2): D package .....	86°C/W
DB package .....	96°C/W
N package .....	80°C/W
NS package .....	76°C/W
Storage temperature range, $T_{stg}$ .....	-65°C to 150°C

† Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. This are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. Voltage values are with respect to network ground terminal.  
2. The package thermal impedance is calculated in accordance with JESD 51-7.

### recommended operating conditions (see Note 3)

	SN5404			SN7404			UNIT
	MIN	NOM	MAX	MIN	NOM	MAX	
$V_{CC}$ Supply voltage	4.5	5	5.5	4.75	5	5.25	V
$V_{IH}$ High-level input voltage	2			2			V
$V_{IL}$ Low-level input voltage	0.8			0.8			V
$I_{OH}$ High-level output current	-0.4			-0.4			mA
$I_{OL}$ Low-level output current	16			16			mA
$T_A$ Operating free-air temperature	-55			0			70 °C

NOTE 3: All unused inputs of the device must be held at  $V_{CC}$  or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

### electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS‡	SN5404			SN7404			UNIT
		MIN	TYP§	MAX	MIN	TYP§	MAX	
$V_{IK}$	$V_{CC} = \text{MIN}$ , $I_I = -12 \text{ mA}$	-1.5			-1.5			V
$V_{OH}$	$V_{CC} = \text{MIN}$ , $V_{IL} = 0.8 \text{ V}$ , $I_{OH} = -0.4 \text{ mA}$	2.4	3.4		2.4	3.4	V	
$V_{OL}$	$V_{CC} = \text{MIN}$ , $V_{IH} = 2 \text{ V}$ , $I_{OL} = 16 \text{ mA}$	0.2	0.4		0.2	0.4	V	
$I_I$	$V_{CC} = \text{MAX}$ , $V_i = 5.5 \text{ V}$	1			1			mA
$I_{IH}$	$V_{CC} = \text{MAX}$ , $V_i = 2.4 \text{ V}$	40			40			$\mu\text{A}$
$I_{IL}$	$V_{CC} = \text{MAX}$ , $V_i = 0.4 \text{ V}$	-1.6			-1.6			mA
$I_{OS}^\parallel$	$V_{CC} = \text{MAX}$	-20			-18			mA
$I_{CCH}$	$V_{CC} = \text{MAX}$ , $V_i = 0 \text{ V}$	6			6			12 mA
$I_{COL}$	$V_{CC} = \text{MAX}$ , $V_i = 4.5 \text{ V}$	18			18			33 mA

‡ For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

§ All typical values are at  $V_{CC} = 5 \text{ V}$ ,  $T_A = 25^\circ\text{C}$ .

¶ Not more than one output should be shorted at a time.



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# Datasheets

- Note 74LS vs. 74
- Supply voltage ( $V_{CC}$ )
- Logic levels ( $V_{IH}$ ,  $V_{IL}$ ,  $V_{OH}$ ,  $V_{OL}$ )
- Currents
  - Output ( $I_{OH}$ ,  $I_{OL}$ ,  $I_{OS}$ )
  - Input ( $I_I$ ,  $I_H$ ,  $I_L$ )
  - Supply ( $I_{CCH}$ ,  $I_{CCL}$ )
- Propagation Delay ( $t_{PLH}$ ,  $t_{PHL}$ )

## SN5404, SN54LS04, SN54S04, SN7404, SN74LS04, SN74S04 HEX INVERTERS

SDLS029C – DECEMBER 1983 – REVISED JANUARY 2004

switching characteristics,  $V_{CC} = 5\text{ V}$ ,  $T_A = 25^\circ\text{C}$  (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	SN5404 SN7404			UNIT
				MIN	TYP	MAX	
$t_{PLH}$	A	Y	$R_L = 400\ \Omega$ , $C_L = 15\ \text{pF}$				ns
$t_{PHL}$				8	15		

recommended operating conditions (see Note 3)

		SN54LS04			SN74LS04			UNIT		
		MIN	NOM	MAX	MIN	NOM	MAX			
$V_{CC}$	Supply voltage	4.5	5	5.5	4.75	5	5.25	V		
$V_{IH}$	High-level input voltage	2						V		
$V_{IL}$	Low-level input voltage	0.7						0.8	V	
$I_{OH}$	High-level output current	-0.4						-0.4	mA	
$I_{OL}$	Low-level output current	4						8	mA	
$T_A$	Operating free-air temperature	-55			125			0	70	$^\circ\text{C}$

NOTE 3: All unused inputs of the device must be held at  $V_{CC}$  or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS†	SN54LS04			SN74LS04			UNIT		
		MIN	TYP‡	MAX	MIN	TYP‡	MAX			
$V_{IK}$	$V_{CC} = \text{MIN}$ , $I_I = -18\ \text{mA}$	-1.5						-1.5	V	
$V_{OH}$	$V_{CC} = \text{MIN}$ , $V_{IL} = \text{MAX}$ , $I_{OH} = -0.4\ \text{mA}$	2.5	3.4		2.7	3.4		V		
$V_{OL}$	$V_{CC} = \text{MIN}$ , $V_{IH} = 2\ \text{V}$ , $I_{OL} = 4\ \text{mA}$ $I_{OL} = 8\ \text{mA}$	0.25			0.4			0.4	V	
$I_I$	$V_{CC} = \text{MAX}$ , $V_I = 7\ \text{V}$	0.1						0.1	mA	
$I_{IH}$	$V_{CC} = \text{MAX}$ , $V_I = 2.7\ \text{V}$	20						20	$\mu\text{A}$	
$I_{IL}$	$V_{CC} = \text{MAX}$ , $V_I = 0.4\ \text{V}$	-0.4						-0.4	mA	
$I_{OS}\S$	$V_{CC} = \text{MAX}$	-20			-100			-20	-100	mA
$I_{CCH}$	$V_{CC} = \text{MAX}$ , $V_I = 0\ \text{V}$	1.2			2.4			1.2	2.4	mA
$I_{CCL}$	$V_{CC} = \text{MAX}$ , $V_I = 4.5\ \text{V}$	3.6			6.6			3.6	6.6	mA

† For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

‡ All typical values are at  $V_{CC} = 5\ \text{V}$ ,  $T_A = 25^\circ\text{C}$ .

§ Not more than one output should be shorted at a time, and the duration of the short-circuit should not exceed one second.

switching characteristics,  $V_{CC} = 5\ \text{V}$ ,  $T_A = 25^\circ\text{C}$  (see Figure 2)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	SN54LS04 SN74LS04			UNIT
				MIN	TYP	MAX	
$t_{PLH}$	A	Y	$R_L = 2\ \text{k}\Omega$ , $C_L = 15\ \text{pF}$				ns
$t_{PHL}$				9	15		
				10	15		



# Datasheets

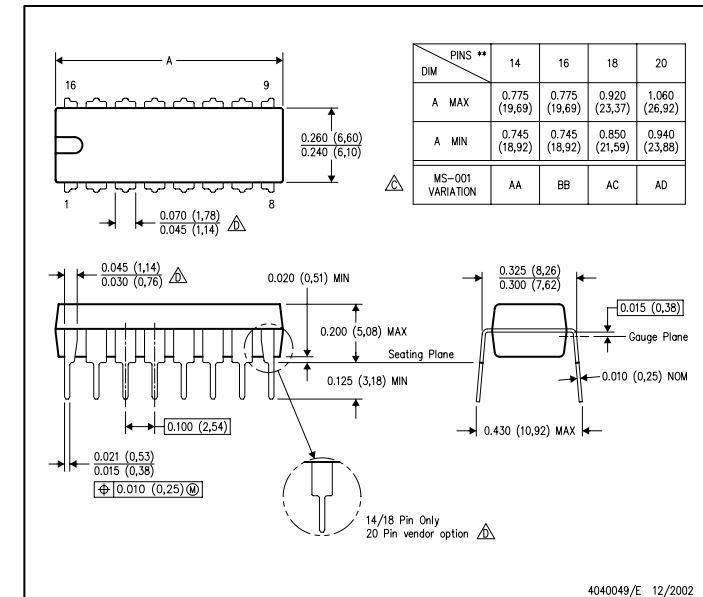
- Mechanical data important when you are designing a printed circuit board.
- Make sure the pins fit your board!

## MECHANICAL DATA

N (R-PDIP-T\*\*)

16 PINS SHOWN

PLASTIC DUAL-IN-LINE PACKAGE

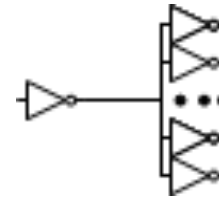


NOTES: A. All linear dimensions are in inches (millimeters).  
B. This drawing is subject to change without notice.  
C. Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).  
D. The 20 pin end lead shoulder width is a vendor option, either half or full width.



# Example: Fanout

**What is the maximum fanout for a 74LS04 NOT gate?**



**Solution:**

**Maximum current into a 74LS04 is  $I_{IL} = 0.4$  mA.**

**Output voltage  $V_{OL}$  is guaranteed at  $I_{OL} = 8$  mA**

**Hence, maximum fanout is  $I_{OL} / I_{IL} = 20$ .**



# Example: Power Consumption

One 74LS04 NOT gate drives 20 identical gates.  $V_{CC} = 5V$ . What is the power consumption of the entire system if the input to the first gate switches at 1 MHz?

## Static Power:

Each gate draws  $I_{CC} = (I_{CCL} + I_{CCH})/2 = (6.6 + 2.4 \text{ mA})/2 = 4.5 \text{ mA}$

$I_{static} = (21 \text{ gates})(4.5 \text{ mA/gate}) = 94.5 \text{ mA}$

$P_{static} = 94.5 \text{ mA} * 5 \text{ V} = 472.5 \text{ mW}$

## Dynamic Power

$C_{in}$  is not specified. Assume  $15 \text{ pF/gate} * 20 \text{ gates} = 300 \text{ pF}$ .

$P = CV_{DD}2f = (300 \times 10^{-12})(5)(1 \times 10^6) = 7.5 \text{ mW}$

$P_{total} = P_{static} + P_{dynamic} = 480 \text{ mW}$

**TTL power is primarily static**

